

Preliminary tests for the development of a beam conditions monitor

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From the Machine interface



Irregular proton losses

Equipment failures
Equipment errors
Operational errors



Danger of damage to accelerator components.

In particular: Collimators
close to beam!

Beam dump: Designed to extract beam within 2 turns.
Pulse rise time of 3 ns (dump gap).

Failure modes:

- **Total failure** of dump or dump trigger (> 100 years)
- Dump action **non-synchronous** with dump gap
- Dump action from **1 of 15 modules**, others retriggering after 1.3 ns.

Difficult to predict
Assume at least once per year!

RA EPAC02

Magnet failures: V. Kain et al, MOPLE032

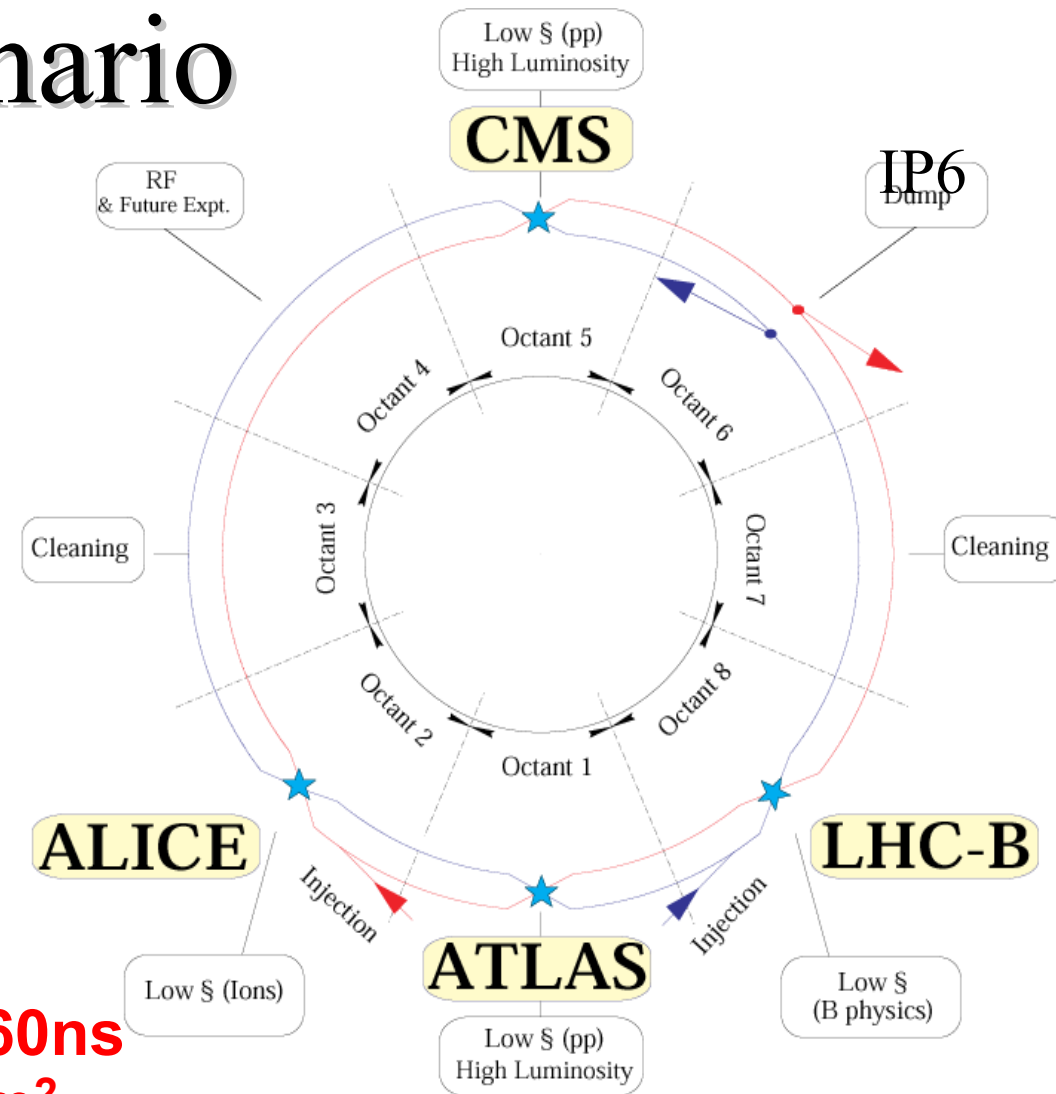
Similar accidents at
CDF and Phobos

Questions

- **What are the scenarios(normal running, ramping, injection)**
 - **Take unsynchronised abort as the worst case**
- **Can silicon strip modules survive unsynchronised beam abort without damage?**
- **What damage could occur**
 - **destroy coupling capacitor on strips**
 - **Over voltage on low voltage supply**
 - **Short circuit of HV \Rightarrow Pinholes**
- **What is the recovery procedure**
- **Can we build a protection mechanism**

Worst Case scenario

- Single module prefire: very unlikely
Assumption only one of the 14 abort kicker fires
=> $4 \cdot 10^{13}$ protons lost in IP 5
- Unsynchronized abort: very likely
Worst case: one of the dump kickers does not hit the abort gap
=> bunch swept out for $\sim 3\mu\text{s}$;
some deviated bunches continue in the machine
=> $1 \cdot 10^{12}$ protons lost in IP 5

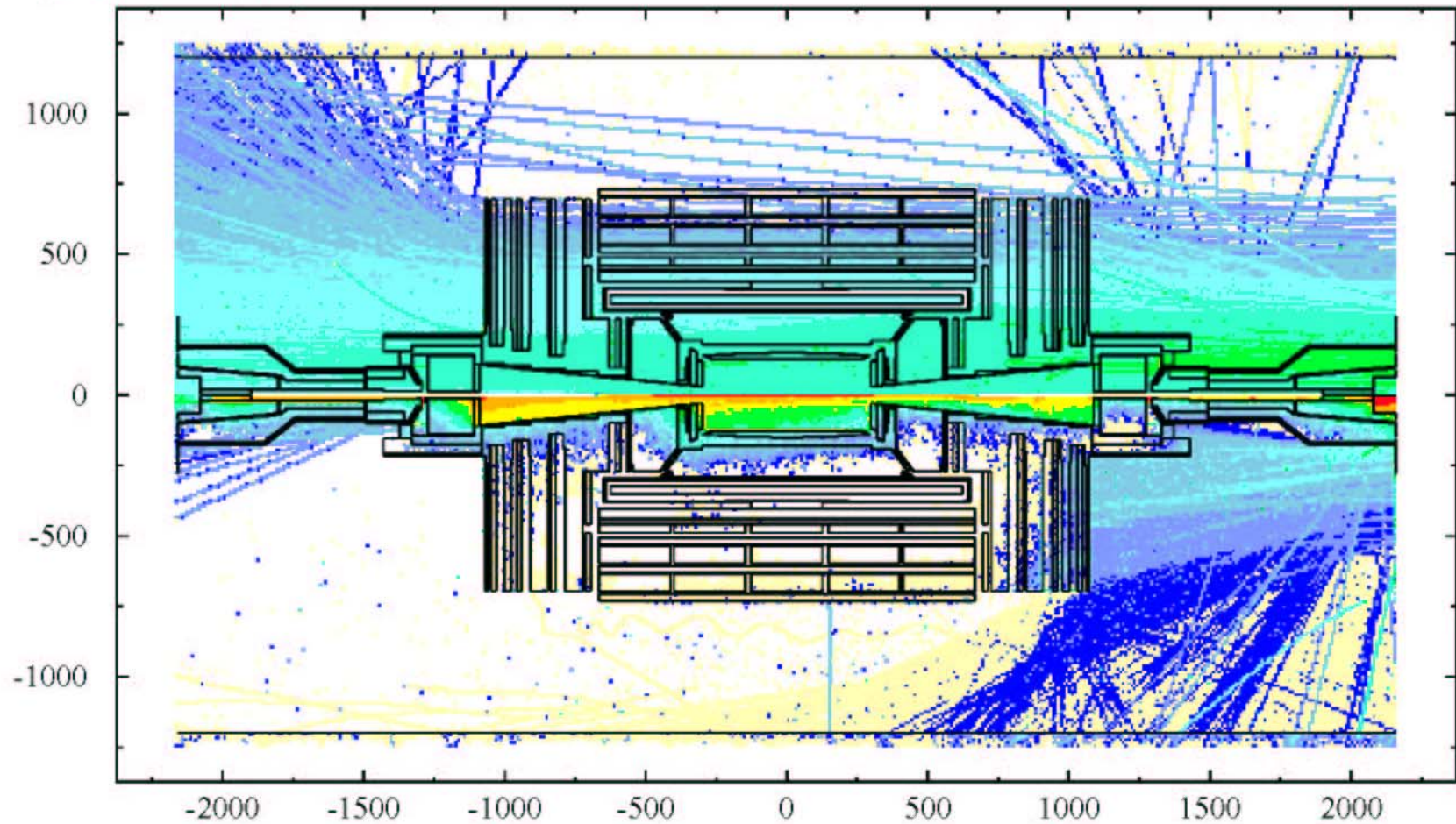


Timescale of accident in CMS $\sim 260\text{ns}$
Characteristic flux 10^9 particles/cm²

Dose per unsynchronized LHC beam abort (Gy)

Upper half: due to muons, Lower half: due to hadrons

M. Huhtinen

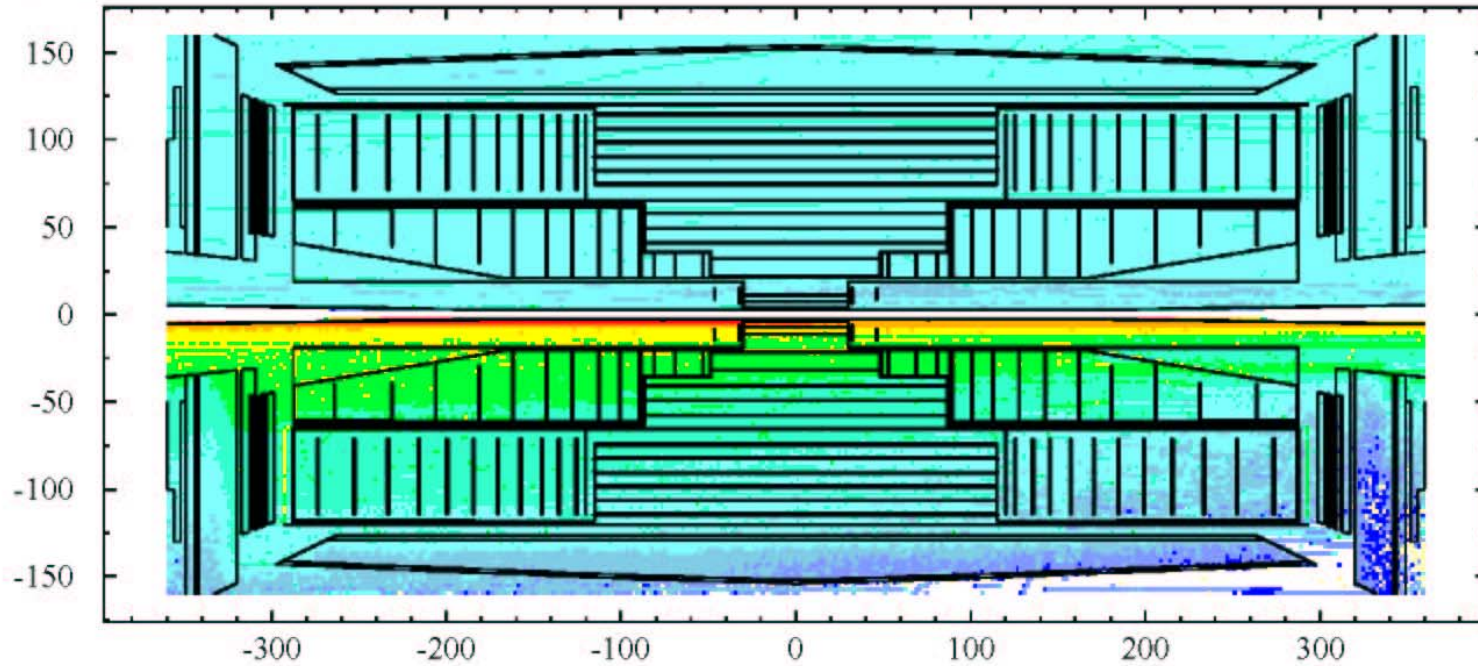


6.5E+00 1.0E+00 1.0E-01 1.0E-02 1.0E-03 1.0E-04 1.0E-05 1.0E-06 1.0E-07 1.0E-08 1.0E-09 1.6E-26

Dose per unsynchronized LHC beam abort (Gy)

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M. Huhtinen



$3.4E+00$ $1.0E+01$ $1.0E+00$ $1.0E-01$ $1.0E-02$ $1.0E-03$ $1.0E-04$ $1.0E-05$ $1.0E-06$ $1.0E-07$ $1.0E-08$ $2.2E-15$

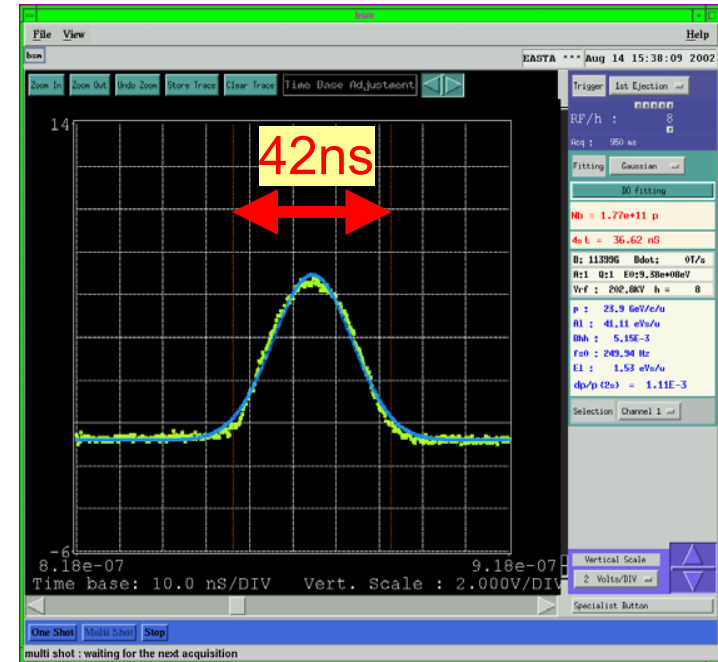
1-Shot test beam at T7 Primary zone

Beam Structure: Two beam configurations built from fast extraction from PS

- **Single bump (1 spill)**
- **Double bump**
2 spills separated by 527ns

→ Approximation to beam accident scenarios

Each spill ~ **3.6×10^{11} protons**

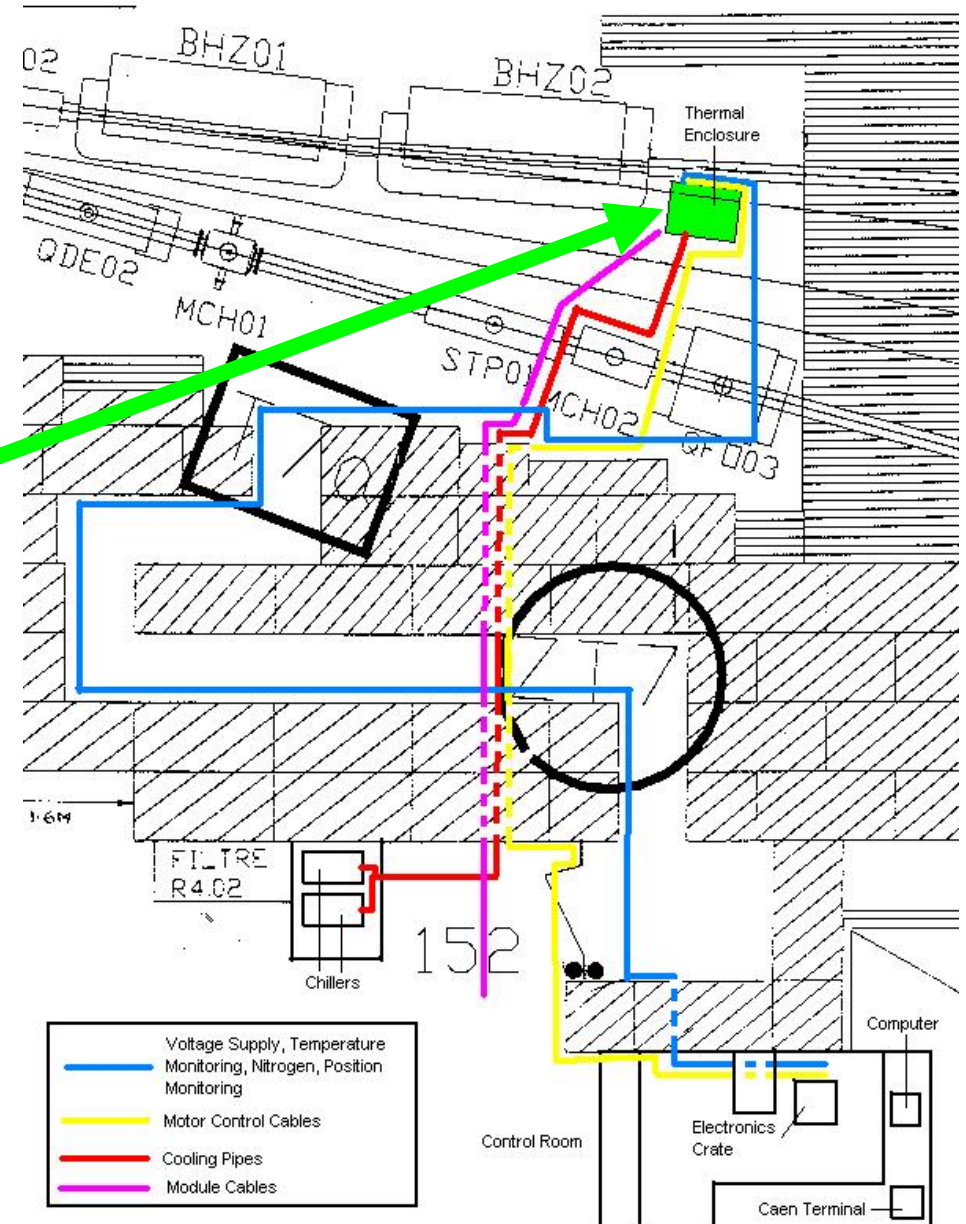
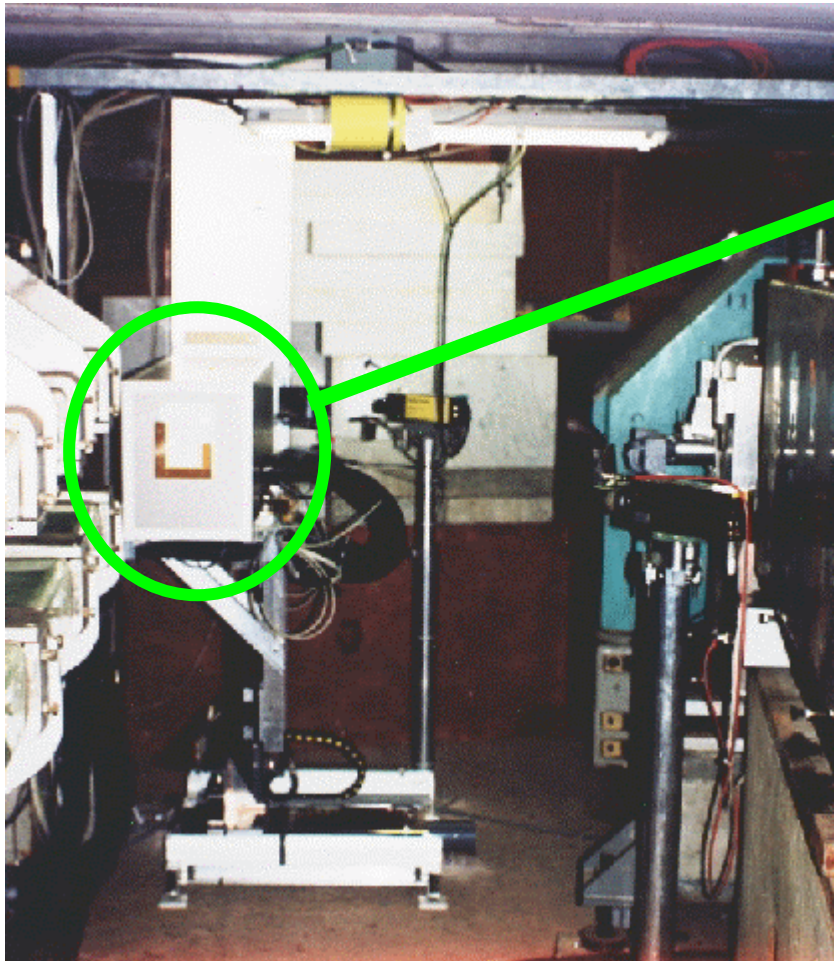


Each spill focus into a large beam spot that completely covers the module. **Reason:** completely destroy field configuration/depletion across entire silicon sensor

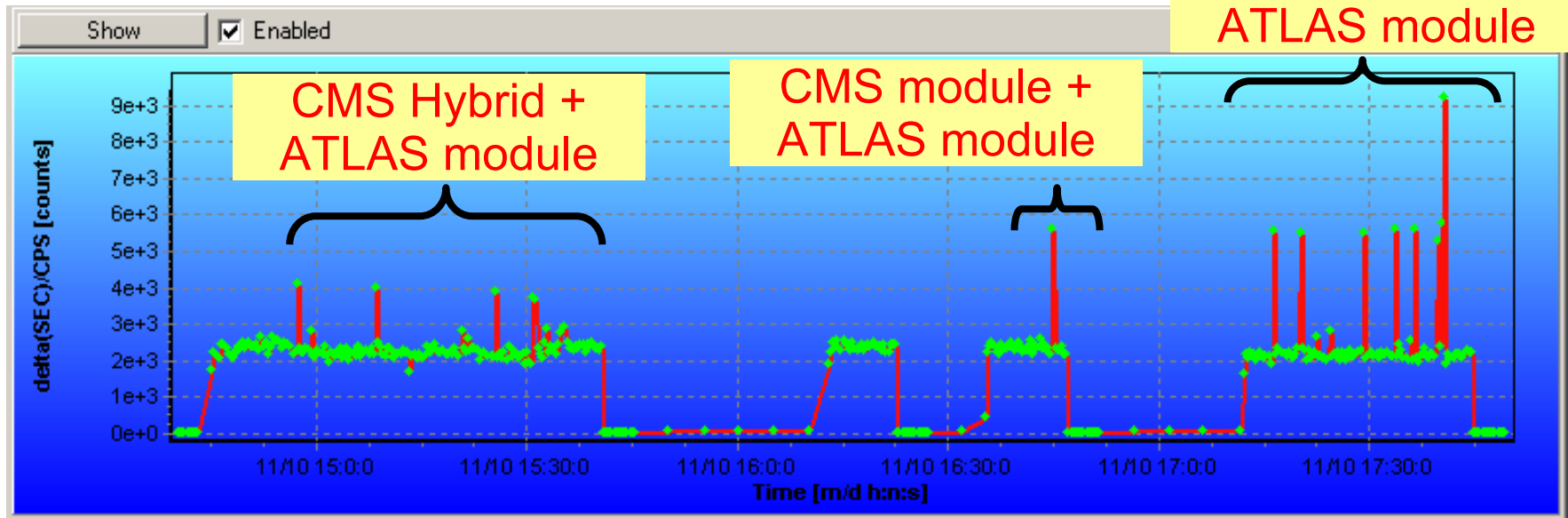
Beam spot = cigar shape 10cm x 3 cm with $> 10^9$ protons/cm²
~ 5×10^9 protons/cm² at centre

East Hall T7 Area

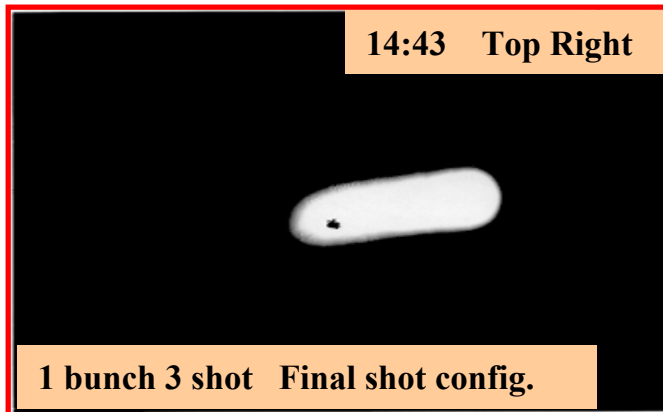
Primary zone with
24GeV proton beam



On line beam monitoring and Dosimetry



No.	Start Time	Stop Time	SEC count	# shots	protons	Error
Carbon #C10	4:45:03 PM	4:45:04 PM	3.38E+03	1 (1x2)	1.34E+09/cm2	8.0%
Aluminium #20	4:45:03 PM	4:45:04 PM	3.38E+03	1 (1x2)	1.34E+09/cm2	20.0%
Aluminium #21	5:13:00 PM	5:39:00 PM	2.43E+04	9 (7x2)	7.98E+11	7.0%
Aluminium #22	2:57:14 PM	3:31:14 PM	8.30E+03	5 (5x 1)	6.03E+11	9.0%
Aluminium #23	4:45:03 PM	4:45:04 PM	3.38E+03	1 (1x2)	1.59E+11	9.0%



For each run, beam position checked with low sensitivity Polaroids

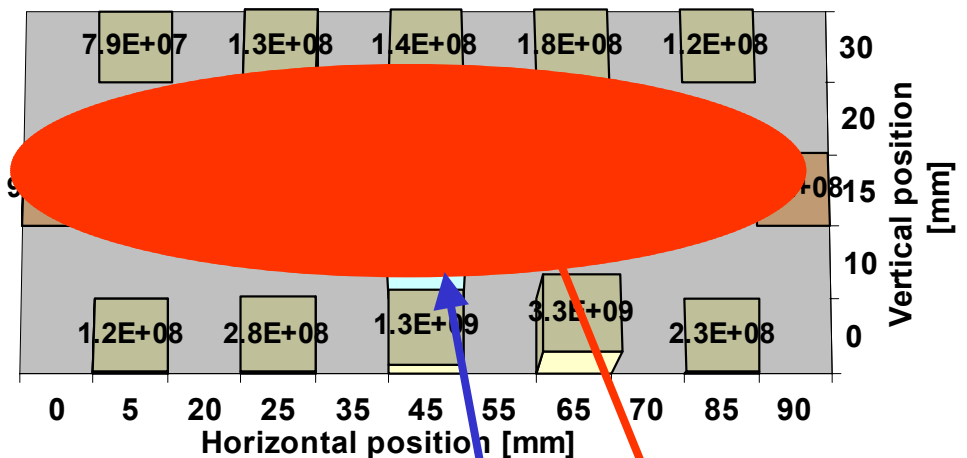
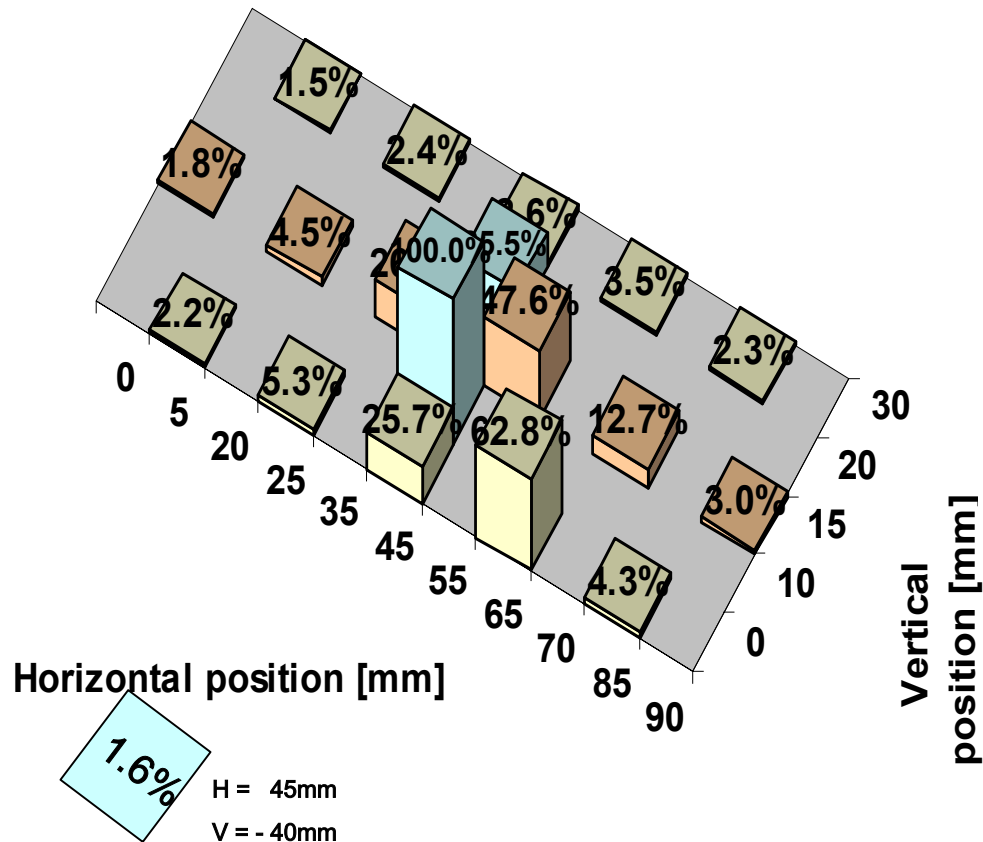
Beam profile in T7

Total fluence = 3.62×10^{11} protons

11 October 2002 16:45:04

Dosimetry and profile obtained by ^{11}C with 15 Carbon blocks $10\text{mm}^2 \times 1\text{mm}$ thick

Gamma dosimetry by germanium spectrometer Ge0



**Beam spot centre
as measured by ^{11}C
dosimetry**

**Central fluence/shot
 $\sim 5.2 \times 10^9$ proton/cm²**

CMS setup

1st test: Hamamatsu sensor + hybrid (flex)

- **Vbias scan: 1-shot (single bump) at 10, 100, 150, 200, 400V**

2nd test: ST-sensor OB2 + TOB module

- **single 1-shot (double bump) at 400V**

3rd test: Hamamatsu sensor + TEC Express Line module

- **Vbias scan: one shot (double bump) at 100 - 500V in 100V-steps**
- **Stress test: 4 consecutive shots (double bumps) at 500V**

Strip parameter on silicon

V_{ACDC} for 3 groups of 5 strips each (Pinhole indicator)

I_{strip} for 3 groups close by (current & Rpoly indicator)

Module / Silicon global parameters

HV as seen by the DUT

I_{leak} via voltage over resistors

Hybrid parameters

V_{125} potential between GND and V_{125}

V_{250} potential between GND and V_{250}



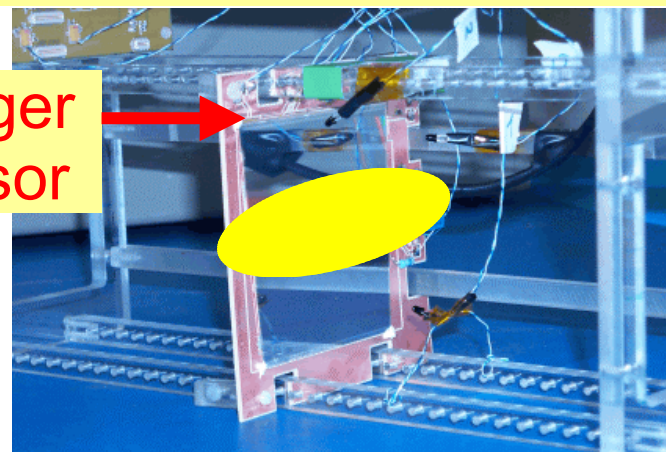
power lines

- Sensed LV for FE
- 2 HV lines (module, sensor)

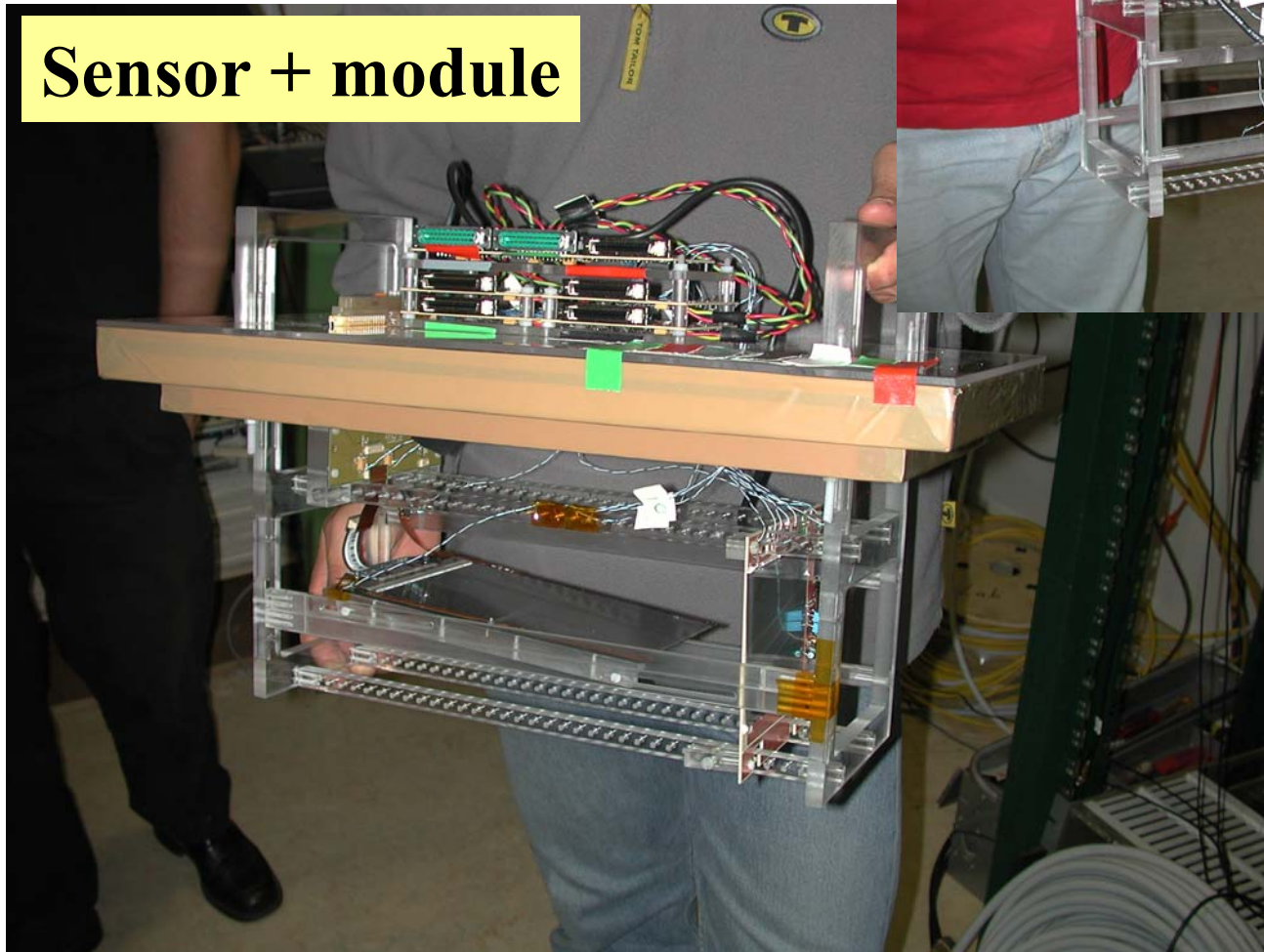
DAQ:

- 38 scope channels. All configured and readout by a single PC.
- All running in 20% pretrigger mode
- All triggered by sensor leakage current
- Optical readout for CMS modules
- Electrical readout for ATLAS modules

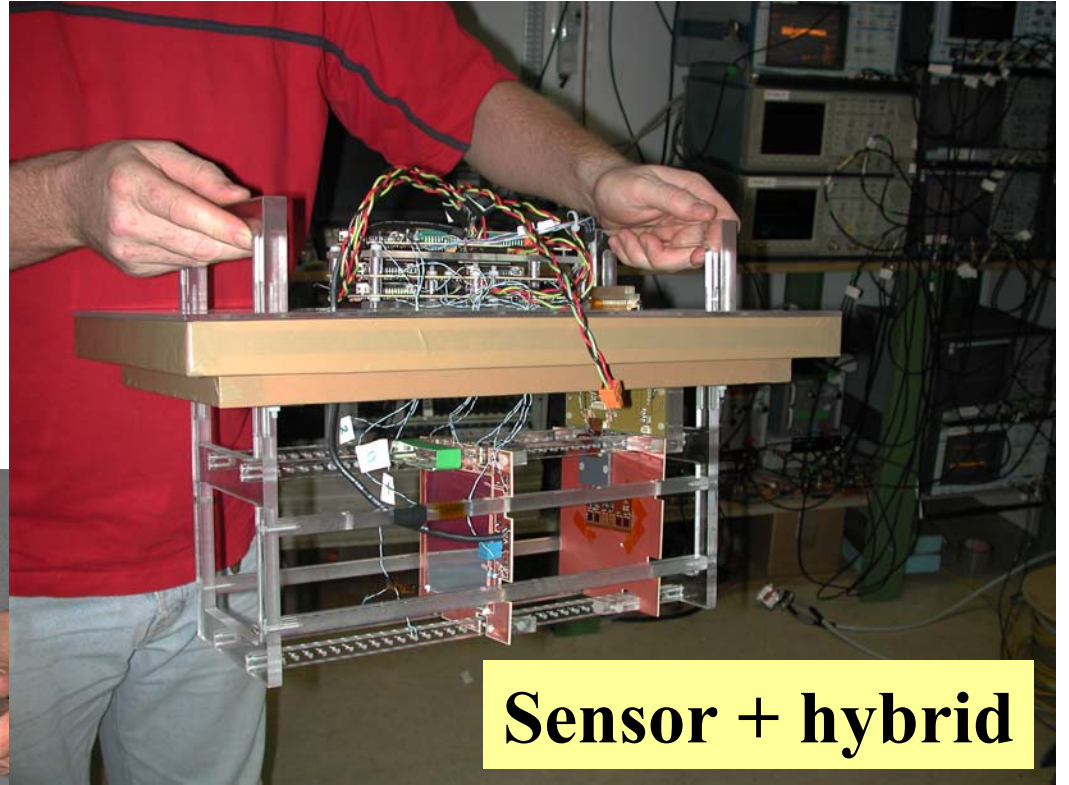
**Trigger
sensor**



Sensor + module



Sensor + hybrid

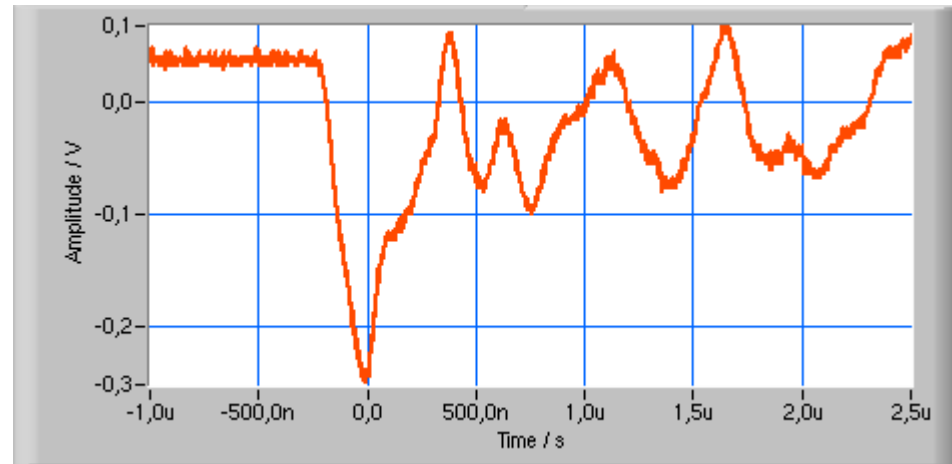


Beam Structure is visible in Data

Single bump

HPK OB2 sensor

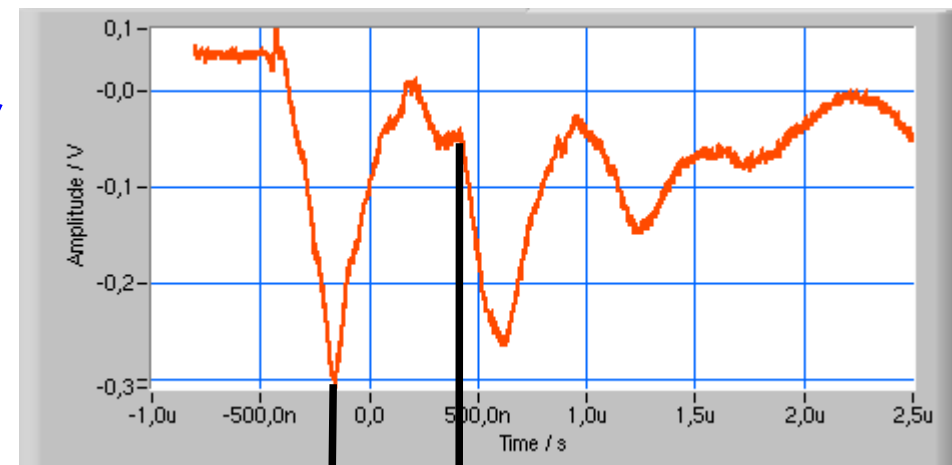
HV breakdown with fast recovery plus add. oscillations



Double bump:

ST W6A sensor

Double HV breakdown



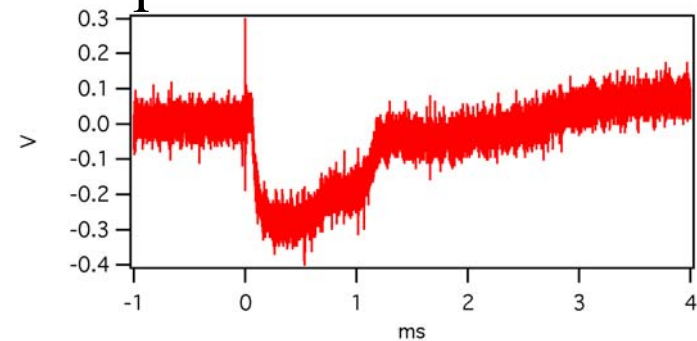
Op-Amp in readout with
bandwidth of 1us

=> Overshoot not real

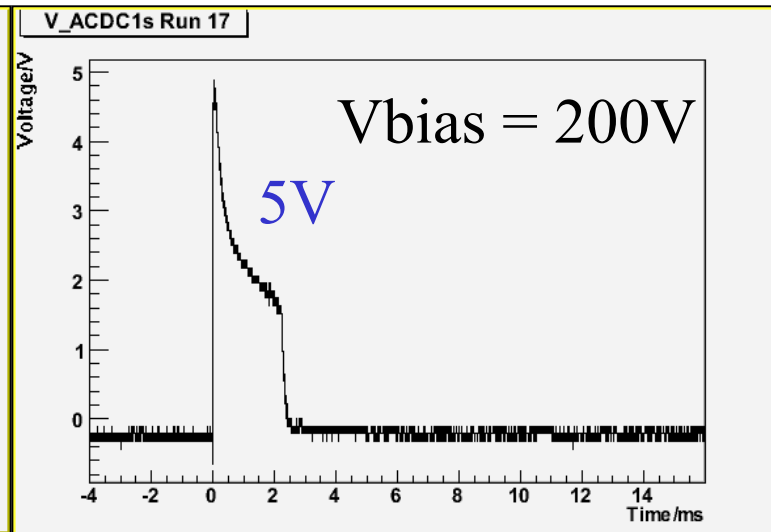
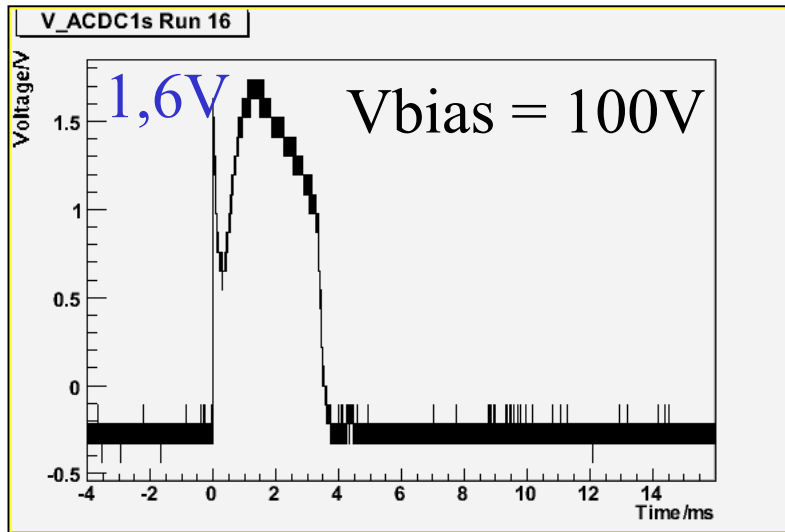
~500ns

ATLAS SCT

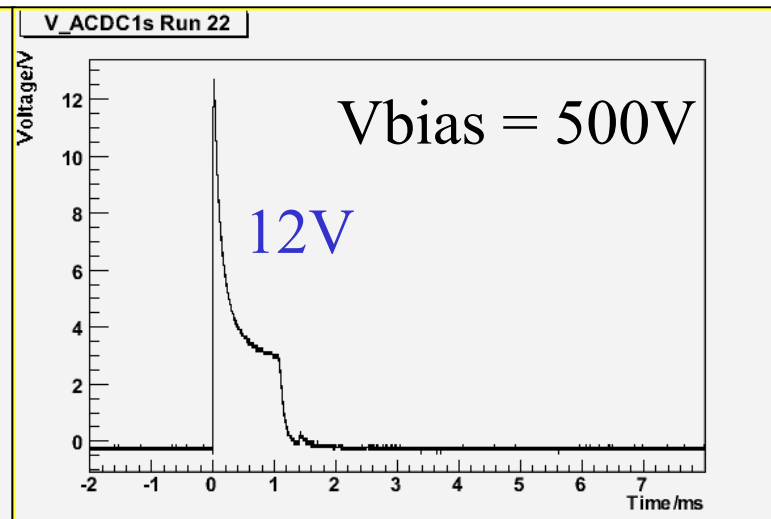
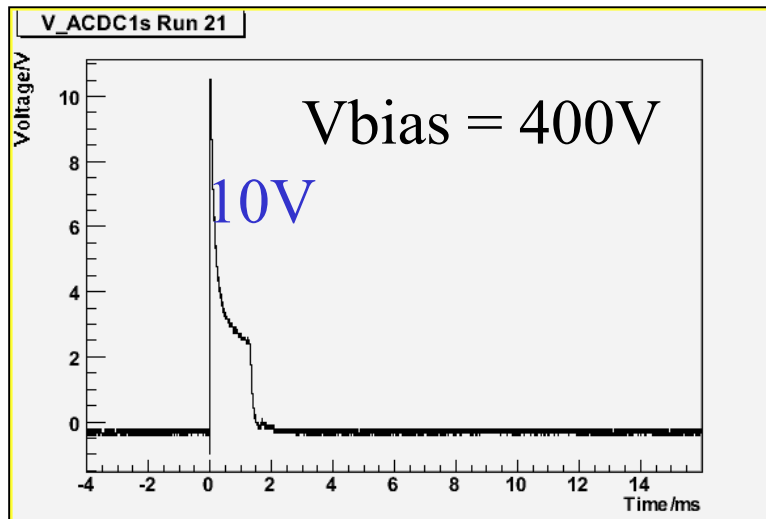
- ATLAS SCT: Electrical test module in standard configuration using 6U VME versions of the final LV and HV power supplies
- 2 configurations tested:
 - with patch panel containing voltage regulators
 - Without voltage regulators
- Results:
 - In all cases the module continued to work normally ie answering to commands and reading out.
 - No resets required
 - With voltage regulators, no voltage excursions.
 - Without voltage regulators, observed voltage excursions on the millisecond time scale
 - 0.3 and 0.1 V excursions on VDD and VCC resp.
 - 6V excursion on the detector HV



CMS: Voltage across coupling capacitors: V_{AC-DC}

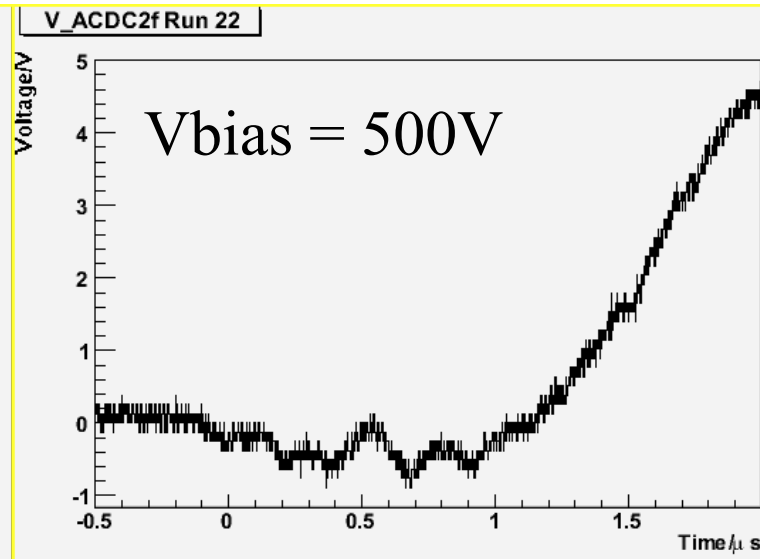
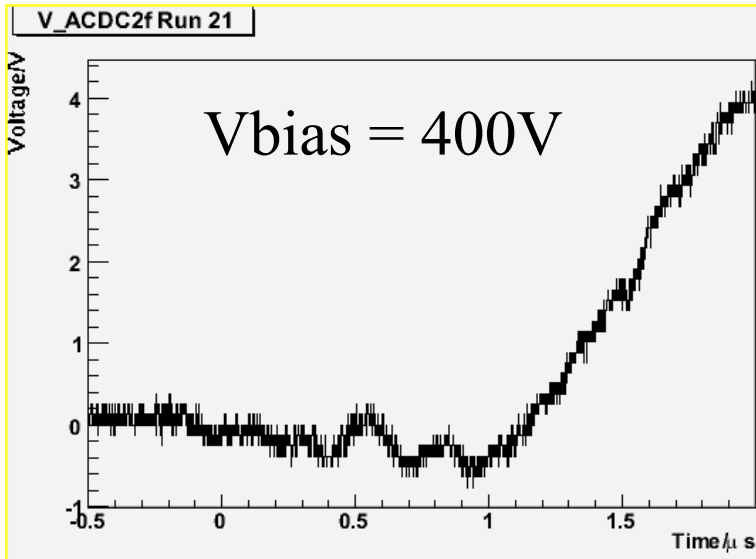
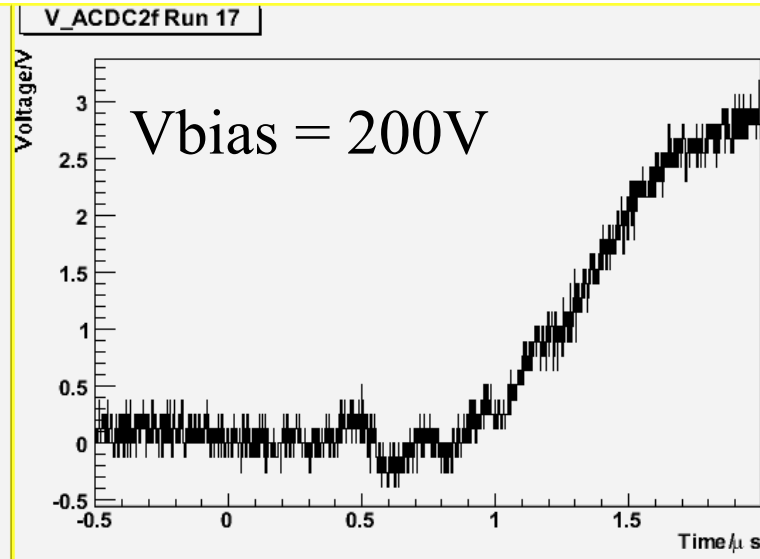
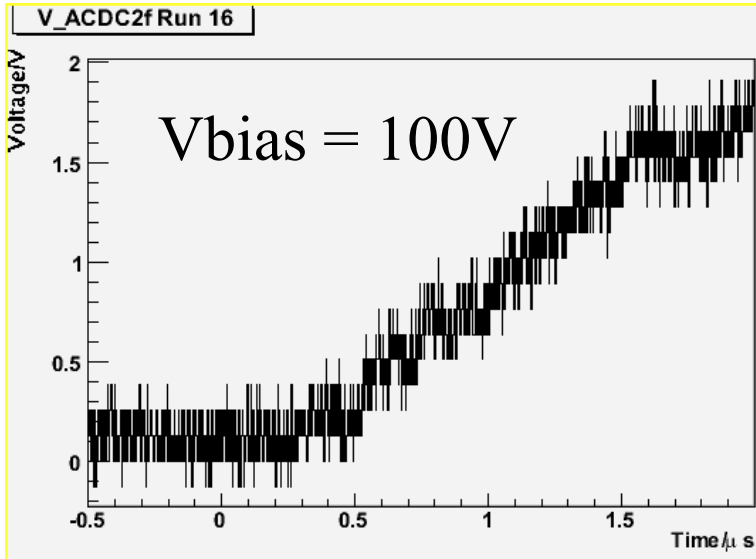


The increase is visible but nowhere critical!



We took these voltages at 3 different places!
Same result (~10%)

Fast view of V_{AC-DC}



V_{ACDC} starts
 $\sim 1 \mu\text{s}$ after
the 1-shot.

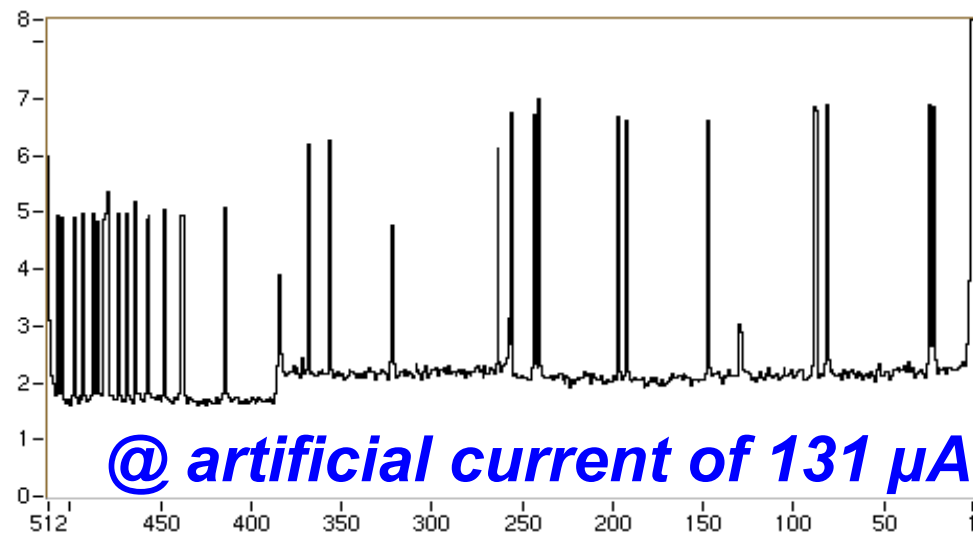
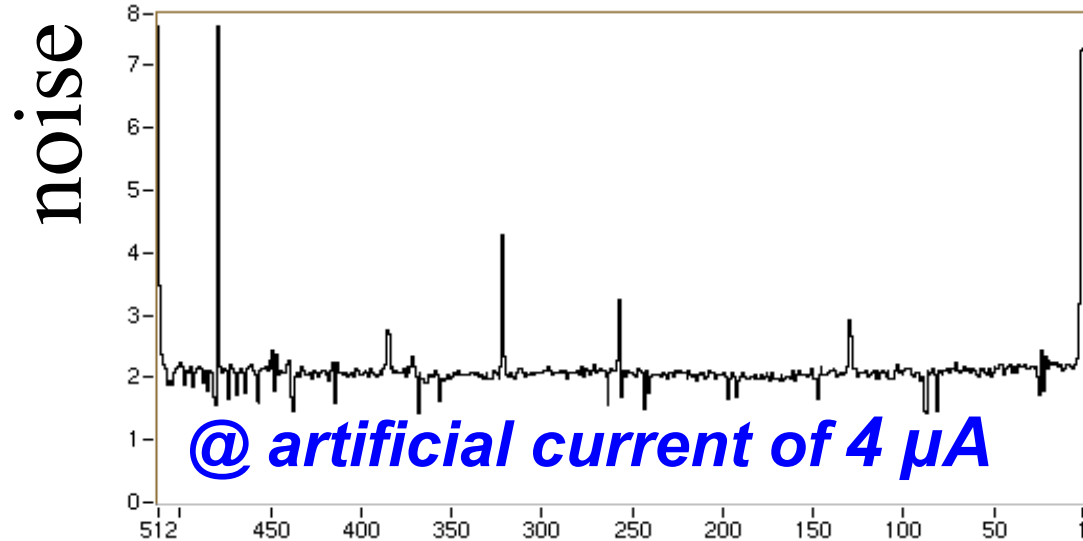
No problem
with spikes
observed

CMS TOB Module

32 pinholes after one shot with $V_{bias} = 400$ V!

Before: 7 bad channels
X5: only some noisy & dead channels

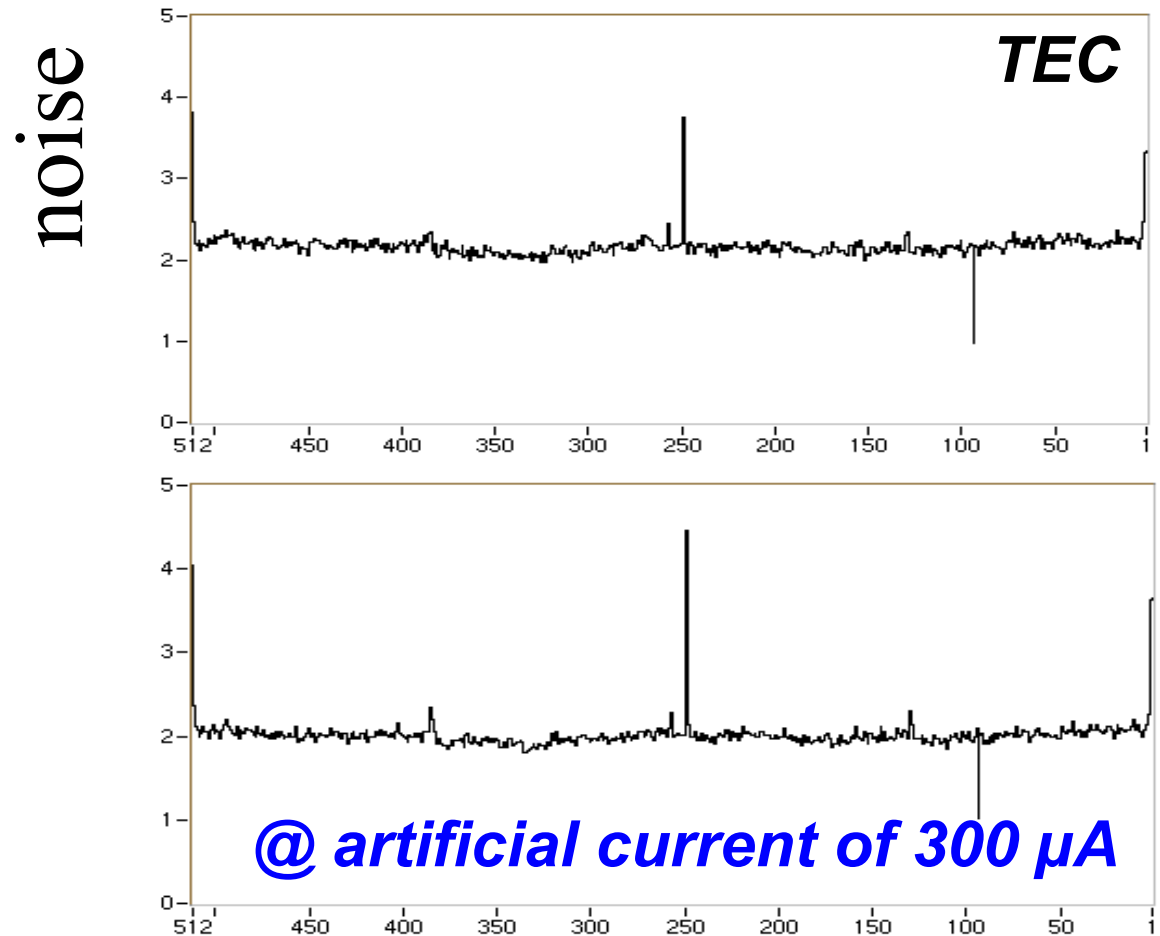
‘Old’ TOB module with M200 sensors from ST used, ***WITHOUT*** the add. SiNitrates in the dielectric (old pinhole problem).



CMS TEC Module

TEC production module:
works fine after a total of 9
“beam dumps”
(including 5 shots @ 500V)

Also no problems with:
Pedestals & Calibration



Sensor requalification

Measurements on Hamamatsu and ST sensors shows:

- slightly **increased leakage current**
- good **CV curves**
- **NO additional pinholes for HPK & ST**
(30 strip sample each)
- **all strip parameters are still in specs**

Some measurement problems due to mounted & glued sensor

Summary of 1-shot tests

- Hybrids

- 5 shots without power +1 shot with power on
- all without clock & I2C

Postqualification in Strasbourg with FHIT shows a perfect working hybrid.

Modules

- survived the electrical stress
- Fast recovery in the range of ms.
- Only soft reset needed
- Fast recovery of electronics and readout

Pixel System Considerations

Dose: ~1 Gy per accident. Corresponds to ~E12 protons

⇒ Unsynch beam abort ⇒ 1×10^{-12} Gy/p.

In 10 years of normal operation CMS pixels expects ~1MGy

⇒ Dose rate = $1 \text{MGy} / 5 \times 10^7 \text{ s} = 0.02 \text{ Gy/s}$ (normal operation @ $1 \text{E}34$).

Assume beam condition monitor with 100 ns integration time

Normal operation: Monitor sees 2×10^{-9} Gy in 100ns

Unsynch beam abort ⇒ loss of $2 \times 10^{-9} / 10^{-12} = 2000$ protons in 100ns

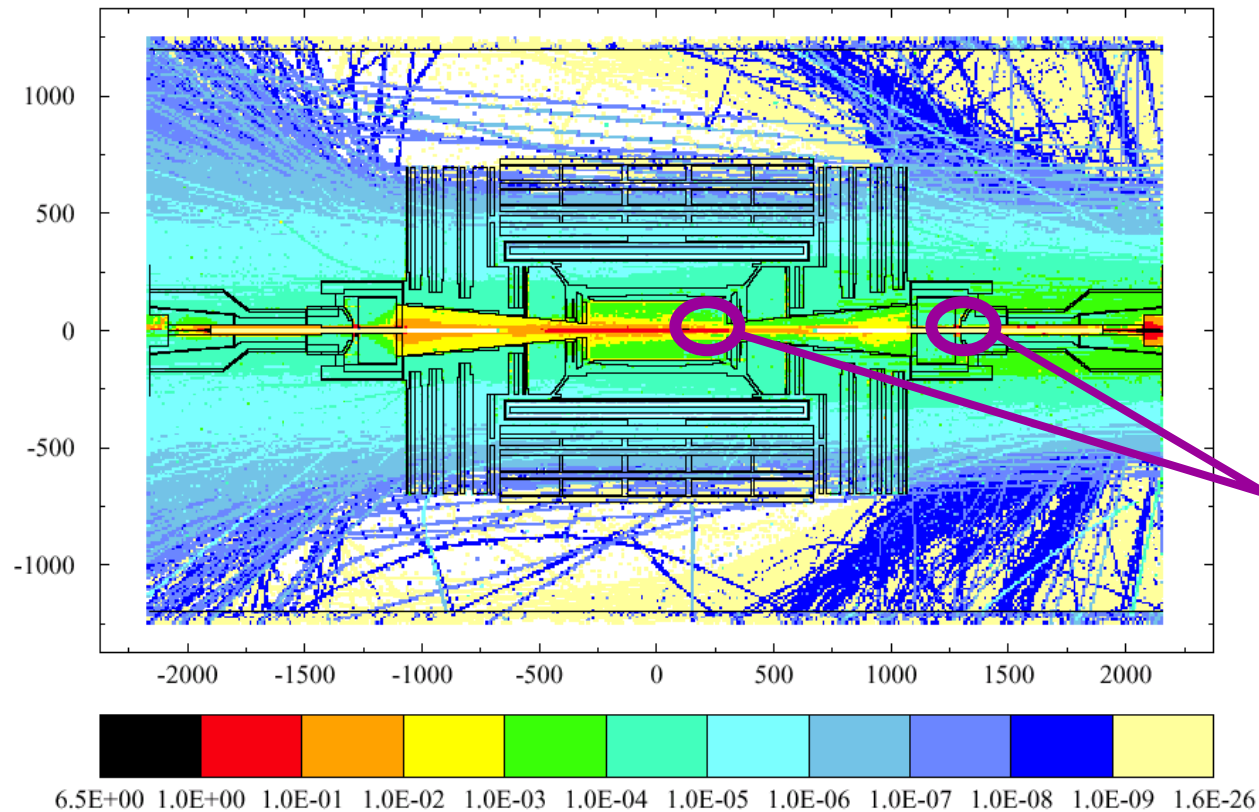
Put a threshold at 1000 protons/100ns. Use to detect fast loss

Power supplies should be able to react on 250 –1000 us

Look to detect fast beam instabilities.

Slowly developing ones difficult to distinguish from the pp-rate

⇒ rely on Machine Group



Beam condition monitors

Looking for increase over normal rate

Monitors to be within CMS volume and feed into machine interlock

Two options being considered to date:

- CVD diamond with 0.25 um readout chip, and readout integrated into pixel system
- Quartz fibre with dedicated opto readout

Very much preliminary: too early to report details